- Maximum Throughput . . . 400 KSPS
- INL/DNL: ±1 LSB Max, SINAD: 72 dB, f<sub>i</sub> = 20 kHz, SFDR: 85 dB, f<sub>i</sub> = 20 kHz
- SPI/DSP-Compatible Serial Interfaces With SCLK up to 20 MHz
- Single 5 V Supply
- Rail-to-Rail Analog Input With 500 kHz BW
- Three Options Available:
   TLC2551 Single Channel Input

- TLC2552 Dual Channels With Autosweep
- TLC2555 Single Channel With Pseudo-Differential Input
- Optimized DSP Mode Requires FS Only
- Low Power With Autopower Down
   Operating Current : 3.5 mA Autopower Down: 8 μA
- Small 8-Pin MSOP and SOIC Packages

	E TOP VIEW C2551	TLC2	2552	TLC	2555
	8] SDO	CS/FS	8] SDO	CS/FS [1	~ 8] SDO
V <sub>REF</sub> [2	7 🛛 FS	V <sub>REF</sub> [2	7 🛛 SCLK	V <sub>REF</sub> [2	7 🛛 SCLK
GND 🛛 3	6 🛛 V <sub>DD</sub>	GND [ 3	6 🛛 V <sub>DD</sub>	GND 🛛 3	6 🛛 V <sub>DD</sub>
AIN 🛛 4	5 ] SCLK	AINO 🛛 4	5 ] AIN1	AIN(+) [ 4	5 ] AIN(–)

#### description

The TLC2551/2552/2555 are a family of high performance, 12-bit, low power, miniature 1.5  $\mu$ s, CMOS analog-to-digital converters (ADC). The TLC255x family uses a 5 V supply. Devices are available with single, dual, or single pseudo-differential inputs. The TLC2551 has a 3-state output chip select ( $\overline{CS}$ ), serial output clock (SCLK), and serial data output (SDO) that provides a direct 3-wire interface to the serial port of most popular host microprocessors (SPI interface). When interfaced with a DSP, a frame sync signal (FS) is used to indicate the start of a serial data frame. The TLV2552/55 have a shared  $\overline{CS}$ /FS terminal.

TLC2551/2/5 are designed to operate with very low power consumption. The power saving feature is further enhanced with an autopower-down mode. This product family features a high-speed serial link to modern host processors with SCLK up to 20 MHz. TLC255x family uses the SCLK as the conversion clock, thus providing synchronous operation allowing a minimum conversion time of 1.5 µs using 20 MHz SCLK.

	PACKAGED DEVICES						
ТА	8-MSOP (DGK)	8-SOIC (D)					
	TLC2551CDGK						
0°C to 70°C	TLC2552CDGK						
	TLC2555CDGK						
	TLC2551IDGK	TLC2551ID					
-40°C to 85°C	TLC2552IDGK	TLC2552ID					
	TLC2555IDGK	TLC2555ID					

#### AVAILABLE OPTIONS



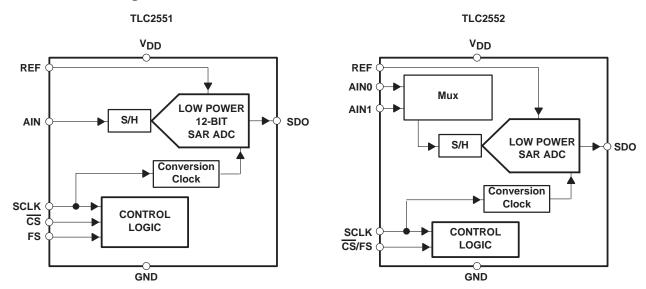
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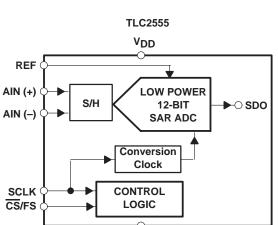
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# functional block diagram





GND



# **Terminal Functions**

## TLC2551

TERMIN	RMINAL		TERMINAL		DECODIDITION
NAME	NO.	1/0	DESCRIPTION		
AIN	4	Ι	Analog input channel		
CS	1	Ι	Chip select. A high-to-low transition on the $\overline{CS}$ input removes SDO from 3-state within a maximum setup time. $\overline{CS}$ can be used as the FS pin when a dedicated serial port is used. If TLC2551 is attached to a dedicated DSP serial port, this terminal can be grounded.		
FS	7	Ι	DSP frame sync input. Indication of the start of a serial data frame. Tie this terminal to $V_{DD}$ if not used.		
GND	3	Ι	Ground return for the internal circuitry. Unless otherwise noted, all voltage measurements are with respect to GND.		
SCLK	5	Ι	Output serial clock. This terminal receives the serial SCLK from the host processor.		
SDO	8	0	The 3-state serial output for the A/D conversion result. SDO is kept in the high-impedance state until $\overline{\text{CS}}$ falling edge. The output format is MSB first.		
			When FS is not used (FS = 1 at the falling edge of $\overline{CS}$ ): The MSB is presented to the SDO pin after $\overline{CS}$ falling edge and output data is valid on the falling edge of SCLK.		
			When FS is used (FS = 0 at the falling edge of $\overline{CS}$ ): The MSB is presented to the SDO pin after the falling edge of FS or the falling edge of $\overline{CS}$ (whichever happens first). Output data is valid on the falling edge of SCLK. (This is typically used with an active FS from a DSP).		
V <sub>DD</sub>	6	Ι	Positive supply voltage		
VREF	2	I	External reference input		

## TLC2552/55

TERMINA	L	I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
AIN0 /AIN(+)	4	Ι	Analog input channel 0. (positive input for TLV2555)
AIN1/AIN (-)	5	Ι	Analog input channel 1 (inverted input for TLV2555)
CS/FS	1	I	Chip select/frame sync. A high-to-low transition on the $\overline{\text{CS}}/\text{FS}$ removes SDO from 3-state within a maximum delay time.
GND	3	Ι	Ground return for the internal circuitry. Unless otherwise noted, all voltage measurements are with respect to GND.
SCLK	7	Ι	Output serial clock. This terminal receives the serial SCLK from the host processor.
SDO	8	0	The 3-state serial output for the A/D conversion result. SDO is kept in the high-impedance state when $\overline{CS}$ /FS is high and presents output data after the $\overline{CS}$ /FS falling edge until the LSB is presented. The output format is MSB first. SDO returns to the Hi-Z state after the 16 <sup>th</sup> SCLK. Output data is valid on the falling SCLK edge.
V <sub>DD</sub>	6	I	Positive supply voltage
V <sub>REF</sub>	2	I	External reference input

## detailed description

The TLC2551/2/5 are successive approximation (SAR) ADCs utilizing a charge redistribution DAC. Figure 1 shows a simplified version of the ADC.

The sampling capacitor acquires the signal on AIN during the sampling period. When the conversion process starts, the SAR control logic and charge redistribution DAC are used to add and subtract fixed amounts of charge from the sampling capacitor to bring the comparator into a balanced condition. When the comparator is balanced, the conversion is complete and the ADC output code is generated.



# detailed description (continued)

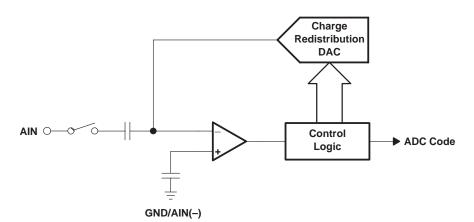


Figure 1. Simplified SAR Circuit

#### serial interface

OUTPUT DATA FORMAT				
MSB	LSB			
D15–D4	D3–D0			
Conversion result (OD11–OD0)	Don't care			

The output data format is binary (unipolar straight binary).

#### binary

Zero scale code = 000h, Vcode = GND Full scale code = FFFh, Vcode = VREFP – 1 LSB

#### pseudo-differential inputs

The TLC2555 operates in pseudo-differential mode. The inverted input is available on terminal 5. It can have a maximum input ripple of  $\pm 0.2$  V. This is normally used for ground noise rejection.

# control and timing

#### start of the cycle

#### TLC2551

- When FS is not used (FS = 1 at the falling edge of CS), the falling edge of CS is the start of the cycle. Output data changes on the rising edge of SCLK. This is typically used for a microcontroller with SPI interface, although it can also be used for a DSP. The microcontroller SPI interface should be programmed for CPOL=0 (serial clock reference to ground) and CPHA=1 (data is valid on the falling edge of serial clock).
- When FS is used (FS is an active signal from a DSP), the falling edge of FS is the start of the cycle. Output data changes on the rising edge of SCLK. This is typically used for a TMS320 DSP. If the TLC2551 is attached to a dedicated DSP serial port. CS terminal can be grounded.

#### TLC2552/5

The  $\overline{CS}$  and FS inputs are accessed via the same pin (pin 1) on the TLC2552 and TLC2555. The cycle is started by the falling edge transition provided by either a  $\overline{CS}$  (interfacing with a SPI interface microcontroller) signal or FS (interfacing with a TMS320 DSP) signal. Timing for the TLC2555 is much like the TLC2551, with the exception of the  $\overline{CS}/FS$  line.



#### detailed description (continued)

### TLC2552 channel MUX reset cycle

The TLC2552 uses  $\overline{CS}/FS$  to reset the AIN multiplexer. A short active  $\overline{CS}/FS$  cycle (4–7 SCLKs) resets the MUX to AIN0. If the  $\overline{CS}/FS$  cycle is sufficient to complete the conversion (16 SCLKs plus maximum conversion time), the MUX toggles to the next channel (see Figure 4 for timing).

#### sampling

The converter sample time is 12 SCLKs beginning on the 5<sup>th</sup> SCLK received after the converter has received an active  $\overline{CS}$  or FS signal ( $\overline{CS}$ /FS for the TLC2552/5).

#### conversion

The TLC2551 completes conversion in the following manner. The conversion is started after the 16th SCLK edge. The conversion takes 1.4  $\mu$ s using 20 MHz SCLK plus 0.1  $\mu$ s overhead. Enough time (for conversion) should be allowed before a rising  $\overline{CS}/FS$  edge so that no conversion is terminated prematurely.

TLC2552 input channel selection is toggled on each rising  $\overline{CS}$  /FS edge. The MUX channel can be reset to AIN0 via  $\overline{CS}$  /FS as described in the earlier section and in Figure 5. The input is sampled for 12 SCLKs, converted, and the result is presented on SDO during the next cycle. Care should also be taken to allow enough time between samples to avoid prematurely terminating the conversion, which occurs on a rising  $\overline{CS}$  /FS transition if the conversion is not complete.



# timing diagrams/conversion cycles

#### **DSP** Interface

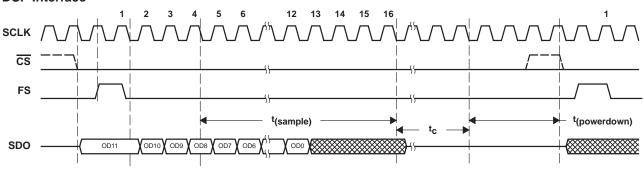
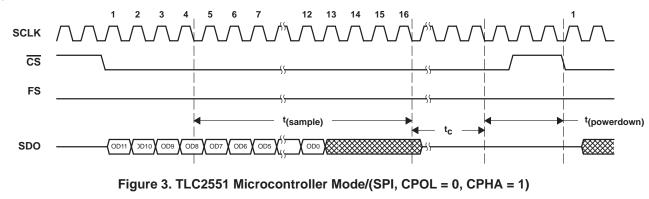
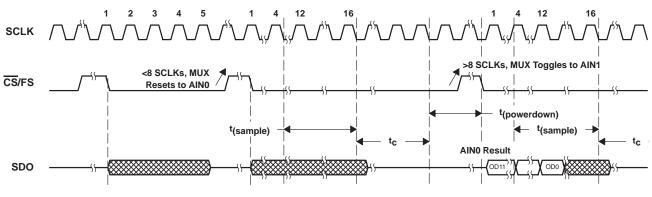


Figure 2. TLC2551 DSP Mode/FS Active

μP Interface



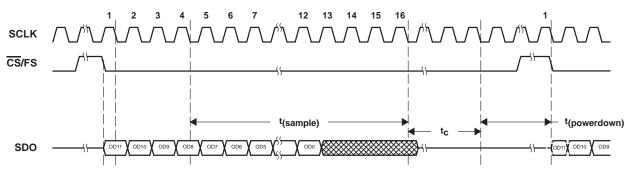


## Figure 4. TLC2552 Timing



SLAS276 – MARCH 2000

#### timing diagrams/conversion cycles (continued)



#### Figure 5. TLC2555 Timing

# use CS as FS input

When interfacing the TLC2551 with the TMS320 DSP, the FSR signal from the DSP may be connected to the CS input if this is the only device on the serial port. This will save one output terminal from the DSP. (Output data changes on the falling edge of SCLK. Default for TLC2552 and TLC2555).

#### SCLK and conversion speed

It takes 14 conversion clocks to complete the conversion. The conversion clock for the TLC2551/2/5 is equal to SCLK/2. This yields a minimum conversion time of 1.4 us plus 0.1 us overhead. These devices can operate with an SCLK up to 20 MHz for the supply voltage range specified. The total conversion time is 14× (1/10M) +16× (1/20M)+ 0.1  $\mu$ s} = 2.3  $\mu$ s for a 20 MHz SCLK. This is the minimum cycle time for an active  $\overline{CS}$  or  $\overline{CS}/FS$ signal. If violated, the conversion will terminate, invalidating the next data output cycle.

#### reference voltage

An external reference is applied via VREF. The voltage level applied to this pin establishes the upper limit of the analog inputs to produce a full-scale reading. The value of V<sub>RFF</sub> and the analog input should not exceed the positive supply or be less than GND, consistent with the specified absolute maximum ratings. The digital output is at full scale when the input signal is equal to or higher than V<sub>REF</sub> and at zero when the input signal is equal to or lower than GND.

#### powerdown and powerup initialization

Autopower down is built in to the devices in order to reduce power consumption. The wake-up time is fast enough to provide power down between each cycle. The power-down state is initiated at the end of conversion and wakes up upon a falling edge on  $\overline{CS}$  or FS.



#### absolute maximum ratings over operating free-air temperature (unless otherwise noted)<sup>†</sup>

Supply voltage range, GND to V <sub>DD</sub>	
Analog input voltage range	$-0.3 \text{ V to V}_{\text{DD}} + 0.3 \text{ V}$
Reference input voltage	V <sub>DD</sub> + 0.3 V
Digital input voltage range	–0.3 V to V <sub>DD</sub> + 0.3 V
Operating virtual junction temperature range, T <sub>J</sub>	–40°C to 150°C
Operating free-air temperature range, T <sub>A</sub> : C	0°C to 70°C
Ι	–40°C to 85°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V <sub>DD</sub>		2.7	3.3	5.5	V
Positive external reference voltage input, VREFP (see Note 1)		2 V <sub>DD</sub> V			V
Analog input voltage (see Note 1)		0		V <sub>DD</sub>	V
High level control input voltage, VIH		2.1			V
Low-level control input voltage, VIL				0.6	V
Setup time, $\overline{CS}$ falling edge (for 2551) or $\overline{CS}$ /FS falling edge (for 2552/55) before first SCLK falling edge, $t_{su(CSL-SCLKL)}$	V <sub>DD</sub> = REF = 5.5 V	40			ns
Hold time, CS rising edge after SCLK falling edge, th(SCLKL-CSH)					ns
Delay time, delay from CS falling edge to FS rising edge (td(CSL-FSH)		0.5		7	SCLKs
Setup time, FS rising edge before SCLK falling edge, t <sub>SU</sub> (FSH-SCLKL)					SCLKs
Hold time, FS hold high after SCLK falling edge, th(SCLKL-FSL)				0.65	SCLKs
Pulse width CS high time, t <sub>wH(CS)</sub>		100			ns
Pulse width FS high time, t <sub>wH(FS)</sub>		0.75			SCLKs
SCLK cycle time, $V_{DD}$ = 5.5–4.5 V, $t_{C(SCLK)}$		50		10000	ns
Pulse width low time, twL(SCLK)		0.4		0.6	SCLKs
Pulse width high time, twH(SCLK)		0.4		0.6	SCLKs
Hold time, hold from end of conversion to CS high, $t_{h}(EOC-CSH)$ (EOC is internal, indicates end of conversion time, $t_{c}$ )		0.1			μs
Active CS/FS cycle time to reset internal MUX to AIN0, reset cycle	TLC2552 only	4		7	SCLKs
Operating free-air temperature, TA	TLC2551/2/5C	0		70	°C
	TLC2551/2/5I	-40		85	U

NOTES: 1. Analog input voltages greater than that applied to VREF convert as all ones (11111111111), while input voltages less than that applied to GND convert as all zeros(0000000000).

2. This is the time required for the clock input signal to fall from V<sub>IL</sub> max or to rise from V<sub>IL</sub>max to V<sub>IL</sub>min. In the vicinity of normal room temperature, the devices function with input clock transition time as slow as 1 µs for remote data-acquisition applications where the sensor and A/D converter are placed several feet away from the controlling microprocessor.



## electrical characteristics over recommended operating free-air temperature range, V<sub>DD</sub> = V<sub>REF</sub> = 4.5 V to 5.5 V, SCLK frequency = 20 MHz (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
VOH	High-level output voltage	V <sub>DD</sub> = 5.5 V, I <sub>OH</sub> = -0.2	mA at 30 pF load	2.4			V
Vol	Low-level output voltage	V <sub>DD</sub> = 5.5 V, I <sub>OL</sub> = 0.8 m	A at 30 pF load			0.4	V
	Off-state output current	$V_{O} = V_{DD}$			1	2.5	
loz	(high-impedance-state)	V <sub>O</sub> = 0	$\overline{CS} = V_{DD}$	-1 -2.5 0.005 2.5		μA	
Ін	High-level input current	$V_{I} = V_{DD}$			0.005	2.5	μΑ
IIL	Low-level input current	V <sub>I</sub> = 0 V			-0.005	2.5	μΑ
ICC	Operating supply current	CS at 0 V,	V <sub>DD</sub> = 4.5 V ~ 5.5 V		3	3.5	mA
	Autopower-down current (0.5 µs inactive)	For all digital inputs,	0.014			8	
ICC(AUTOPWDN)	Autopower-down current (5 µs inactive)		$0 \le V_{I} \le 0.3 \text{ V or } V_{I} \ge V_{DD} - 0.3 \text{ V},$ SCLK = 0, $V_{DD} = 4.5 \text{ V to } 5.5 \text{ V},$ Ext ref			1	μA
	Selected analog input channel leakage	Selected channel at V <sub>DD</sub>				1	
	current	Selected channel at 0 V			-1	μA	
C <sub>i</sub>		Analog inputs		20	45	50	
	Input capacitance	Control Inputs			5	25	pF
	Input on resistance	V <sub>DD</sub> = 5.5 V				500	Ω
	Delay time, delay from CS falling edge to SDO valid, td(CSL-SDOV)	V <sub>DD</sub> = REF = 5.5 V, 30 pl	F			40	ns
	Delay time, delay from FS falling edge to SDO valid, td(FSL-SDOV)	V <sub>DD</sub> = REF = 5.5 V, 30 pl	F			1	ns
	Delay time, delay from SCLK rising edge to SDO valid, td(SCLKH-SDOV)	V <sub>DD</sub> = REF = 5.5 V, 30 pl	F			11	ns
	Delay time, delay from 17 <sup>th</sup> SCLK rising edge to SDO 3-state, t <sub>d</sub> (SCLK17H-SDOZ)	V <sub>DD</sub> = REF = 5.5 V, 30 pl	F			30	ns
t <sub>c</sub>	Conversion time	Conversion clock = interna	al oscillator		28		SCL
t(sample)	Sampling time	See Note 3		300			ns
,	Action time	I <sub>CC</sub> start to decrease			0.5		SCL
Autopower down	Wakeup time	ICC down to MIN [ICC(AL	JTOPWDN)]		1	2	ms
	Autopower down				0.5		SCL

<sup>†</sup> All typical values are at V<sub>DD</sub> = 5 V, T<sub>A</sub> = 25°C. NOTE 3: Minimal t<sub>(sample)</sub> is given by  $0.9 \times 50 \text{ pF} \times (R_S + 0.5 \text{ k}\Omega)$ , where R<sub>S</sub> is the source output impedance.



# ac specifications (f<sub>i</sub> = 20 kHz)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SINAD	Signal-to-noise ratio + distortion	400 KSPS, V <sub>DD</sub> = V <sub>REF</sub> = 5 V	70	72		dB
THD	Total harmonic distortion	400 KSPS, V <sub>DD</sub> = V <sub>REF</sub> = 5 V		-84	-80	dB
ENOB	Effective number of bits	400 KSPS, V <sub>DD</sub> = V <sub>REF</sub> = 5 V		11.8		Bits
SFDR	Spurious free dynamic range	400 KSPS, V <sub>DD</sub> = V <sub>REF</sub> = 5 V		-84	-80	dB
Analog	Input					
	Full power bandwidth, –3 dB			1		MHz
	Full-power bandwidth, –1 dB			500		kHz

## external reference specifications

	PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
	Reference input voltage	V <sub>DD</sub> = =4.5 V ~ 5.5 V				V <sub>DD</sub>	V
	Poforonce input impodence		CS = 1, SCLK = 0	100			MΩ
	Reference input impedance	V <sub>DD</sub> = 5.5 V	CS = 0, SCLK = 20 MHz	20	25		kΩ
	Reference current	V <sub>DD</sub> = V <sub>REF</sub> = 5.5 V			100	400	μΑ
			CS = 1, SCLK = 0	5		15	~ 5
	Reference input capacitance	$V_{DD} = V_{REF} = 5.5 V$	CS = 0, SCLK = 20 MHz	20	45	50	pF
VREF	Reference voltage	V <sub>DD</sub> = =4.5 V - 5.5 V				VDD	V

# dc specification, $V_{DD} = V_{REF} = 4.5$ V to 5.5 V, SCLK frequency = 20 MHz (unless otherwise noted)

	PARAMETER		ONDITIONS	MIN	NOM	MAX	UNIT
INL	Integral linearity error (see Note 5)				±0.6	±1	LSB
DNL	Differential linearity error	See Note 4			±0.5	±1	LSB
<b>F</b> •	Offect error (and Note C)	Can Note 4	TLC2551/52			±1.5	
EO	O Offset error (see Note 6) See Note 4		TLC2555			±2.5	LSB
5.0	Gain error (see Note 6)	See Note 4	TLC2551/52			±2	LSB
EG	Gain error (see Note 6)	See Note 4	TLC2555			±5	LOD
E.	E Tatal una diversa (and Nato 7)		TLC2551/52			±2	LSB
Et	Total unadjusted error (see Note 7)	See Note 4	TLC2555			±5	LOD

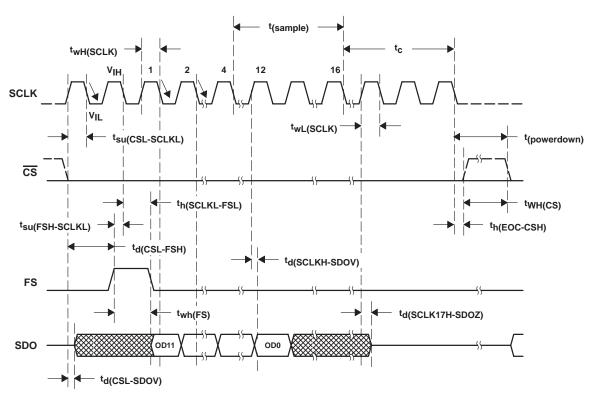
NOTES: 4. Analog input voltages greater than that applied to REFP convert as all ones (11111111111), while input voltages less than that applied to REFM convert as all zeros (000000000).

5. Linear error is the maximum deviation from the best straight line through the A/D transfer characteristics.

6. Zero error is the difference between 0000000000 and the converted output for zero input voltage: full-scale error is the difference between 11111111111 and the converted output for full-scale input voltage.

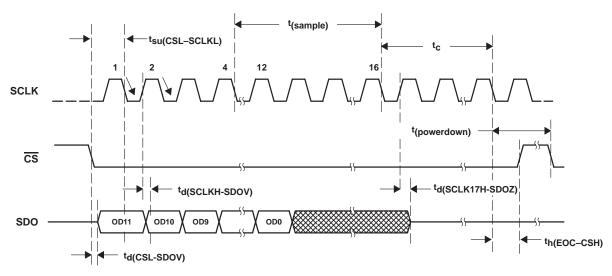
7. Total unadjusted error comprises linearity, zero, and full-scale errors.





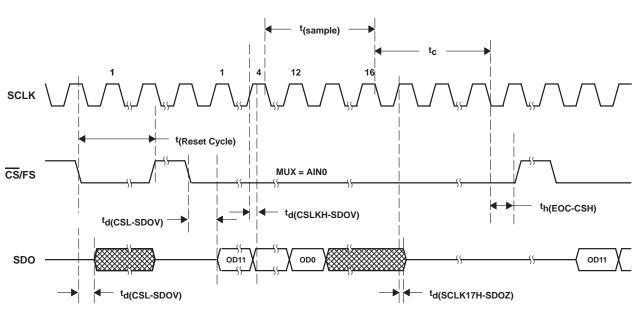
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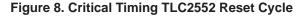


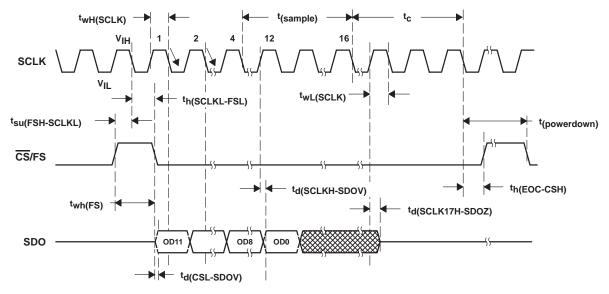






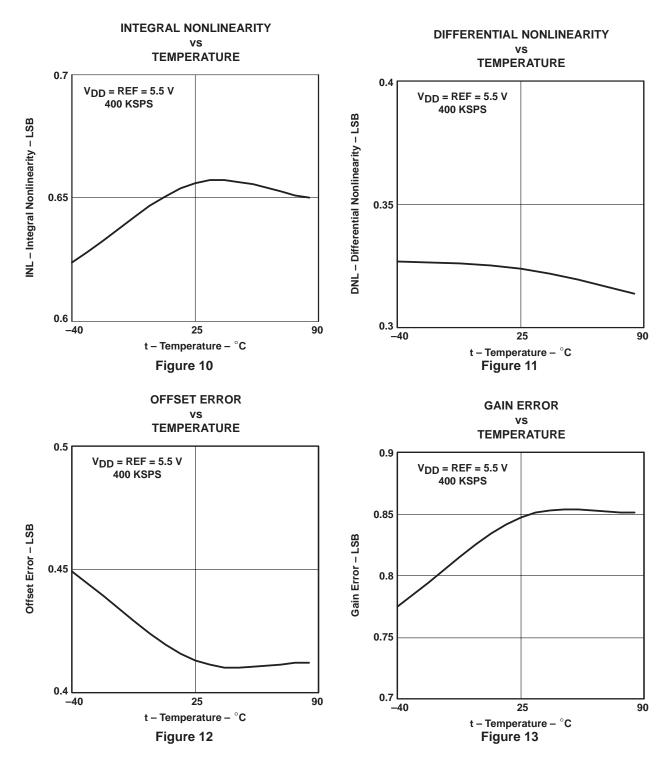
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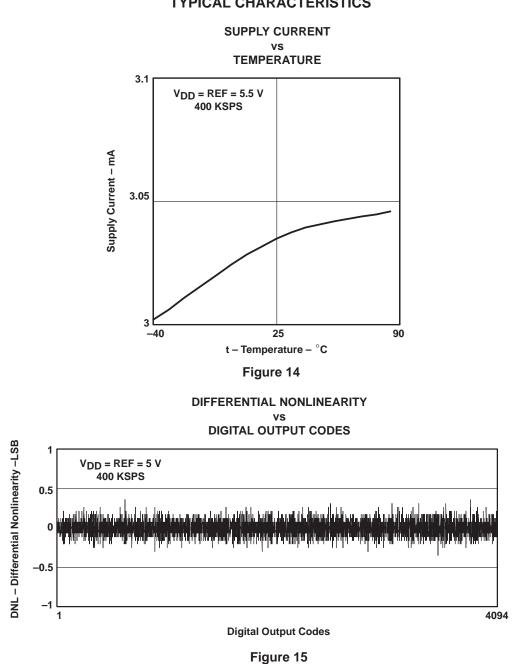






# **TYPICAL CHARACTERISTICS**

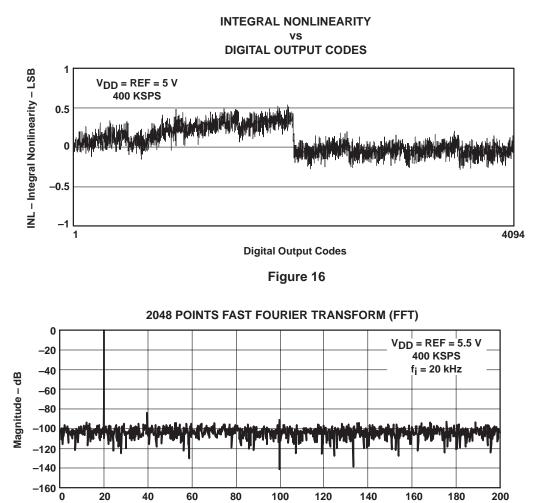




## **TYPICAL CHARACTERISTICS**

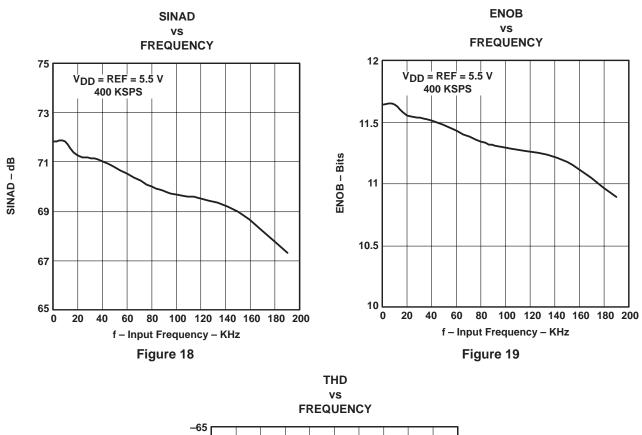


## **TYPICAL CHARACTERISTICS**



f – Input Frequency – KHz Figure 17





# **TYPICAL CHARACTERISTICS**

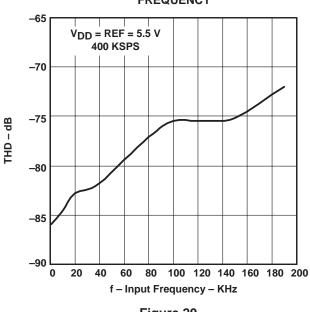
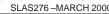
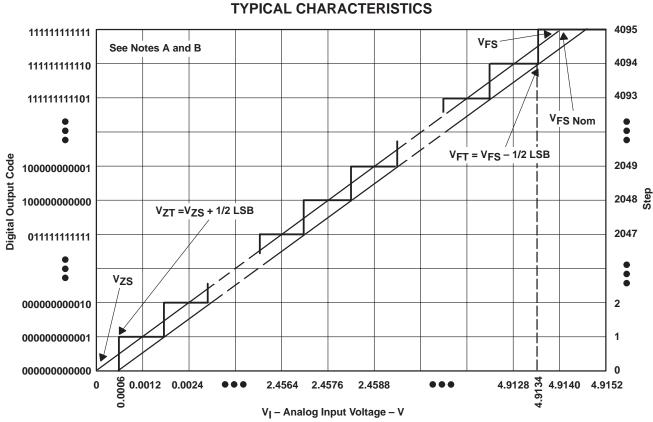


Figure 20







NOTES: A. This curve is based on the assumption that V<sub>ref+</sub> and V<sub>ref+</sub> have been adjusted so that the voltage at the transition from digital 0 to 1 (V<sub>ZT</sub>) is 0.0006 V, and the transition to full scale (V<sub>FT</sub>) is 4.9134 V, 1 LSB = 1.2 mV.

B. The full scale value (VFS) is the step whose nominal midstep value has the highest absolute value. The zero-scale value (VZS) is the step whose nominal midstep value equals zero.

#### Figure 21. Ideal 12-Bit ADC Conversion Characteristics



#### VDD EXT **10 k**Ω 10 k $\Omega$ Reference VDD XF FS V<sub>REF</sub> RXD TMS320 DSP SDO SCLK SCLK TLC2551 cs Ain GND VDD EXT Ş ≶ **10 k**Ω 10 k $\Omega$ Reference VDD XF CS/FSD VREF RXD TMS320 DSP SDO SCLK SCLK TLC2552/55 AIN 0/AIN (+)<sup>†</sup> AIN 1/AIN (-)† GND

**APPLICATION INFORMATION** 

<sup>†</sup> For TLC2555 only



## simplified analog input analysis

Using the equivalent circuit in Figure 23, the time required to charge the analog input capacitance from 0 to Vs within 1/2 LSB can be derived as follows.

The capacitance charging voltage is given by:

$$Vc = Vs \left( 1 - EXP \left( \frac{-tch}{Rt \times Ci} \right) \right)$$
(1)

Where:

Rt = Rs + Zi tch = Charge time

The input impedance Zi is 0.5 k $\Omega$  at 5 V, and is higher (~ 0.6 k $\Omega$ ) at 2.7 V. The final voltage to 1/2 LSB is given by:

$$Vc (1/2 LSB) = Vs - \left(\frac{Vs}{8192}\right)$$
(2)



#### **APPLICATION INFORMATION**

#### simplified analog input analysis (continued)

Equating equation 1 to equation 2 and solving for cycle time t<sub>c</sub> gives:

$$Vs - \left(\frac{VS}{8192}\right) = Vs \left(1 - EXP\left(\frac{-tch}{Rt \times Ci}\right)\right)$$
(3)

and time to change to 1/2 LSB (equal to minimum sampling time) is:

 $tch (1/2 LSB) = Rt \times Ci \times In(8192) = Min[t(sample)]$ 

Where:

ln(8192) = 9.011

Therefore, with the values given, the time for the analog input signal to settle is:

$$tch (1/2 \ LSB) = (Rs + 0.5 \ k\Omega) \times Ci \times In(8192)$$
 (4)

This time must be less than the converter sample time shown in the timing diagrams. This is 12× SCLKs.

$$t_{(sample)} = 12 \times \frac{1}{f(SCLK)} \ge Min \left[ t_{(sample)} \right] = tch \left( \frac{1}{2} \ LSB \right)$$
(5)

Therefore the maximum SCLK frequency is:

$$max \left[ f_{(SCLK)} \right] = \frac{12}{tch \ (1/2 \ LSB)} = \frac{12}{[In(8192) \times Rt \times Ci]}$$
(6)

#### maximum conversion throughput

For a supply voltage of 5 V, if the source impedance is less than 1 k $\Omega$ , and the ADC analog input capacitance Ci is less than 50 pF, this equates to a minimum sampling time tch  $\left(\frac{1}{2} \ LSB\right)$  of 0.676 µs (<1 µs). Since the sampling time requires 12 SCLKs, the fastest SCLK frequency is 12 tch $\left(\frac{1}{2} \ LSB\right)$  = 12 MHz for R<sub>s</sub> ≤ 1 k $\Omega$ .

The minimal total cycle time, t<sub>(cycle)</sub>, is given as:

$$t_{(cycle)} = t_{(sample)} + t_{c} + t_{(overhead)} = \frac{16}{Max \left[ f(SCLK) \right]} + \frac{14}{f[(SCLK)] \times 0.5} + 0.1 \ \mu s = 3.77 \ \mu s$$

This is equivalent to a maximum throughput, max[fs] of 265 KSPS.

The throughput can be even higher with a smaller source impedance. When source impedance is 100  $\Omega$ , the minimum sampling time becomes:

tch (1/2 LSB) = 
$$Rt \times Ci \times In(8192) = 0.27 \ \mu s$$



# **APPLICATION INFORMATION**

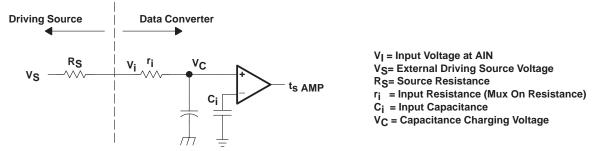
## maximum conversion throughput (continued)

The maximum SCLK frequency possible is 12/tch  $(\frac{1}{2} LSB) = 44$  MHz. Then a 20 MHz clock (maximum SCLK frequency allowed for the internal comparator can be used. The minimal total cycle time is then reduced to:

 $t_{(cycle)} = t_{(sample)} + tc + t_{overhead} = \frac{16}{max \left[f(SCLK)\right]} + \frac{16}{max \left[f(SCLK)\right]/2} + 0.1 \ \mu s = 2.3 \ \mu s$ 

The maximum throughput, MAX[fs], is  $1/2.3 \,\mu$ s = 134 KSPS for this case.

**Driving Source Requirements:** 



NOTE: Noise and distortion must for the source be equivalent to the resolution of the converter.  $R_s$  must be real at the input frequency.

#### Figure 23. Equivalent Input Circuit Including the Driving Source

#### power down calculations

Total power consumption at different conversion rate  $f_s$ , ( $f_s \leq MAX [f_s]$ ) can be calculated by:

 $V_{DD} \times i(AVERAGE) = V_{DD} [(f_S/MAX [f_s]) \times i(ON) + (1-f_s/MAX [f_s]) \times i(OFF)]$ 

If  $V_{DD}$  = 5 V for TLC2551, and the sampling rate  $f_s$  = 10 kHz, the maximum sampling rate  $f_{SMAX}$  = 200 kHz

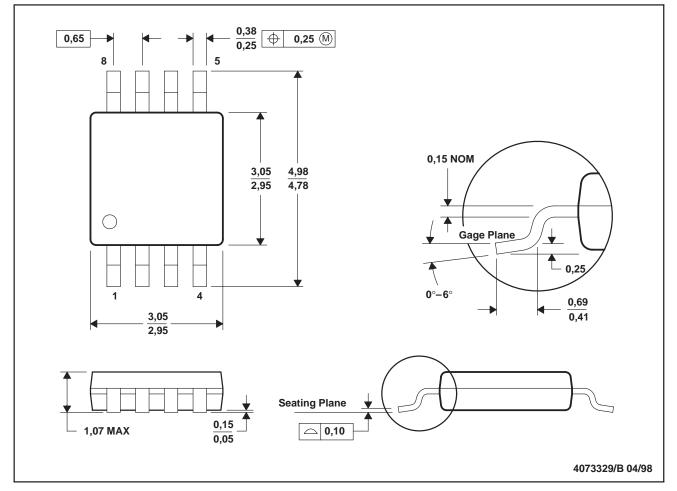
then i(ON) = ~3.5 mA operating current and i(OFF) = ~8  $\mu$ A auto-powerdown current so V<sub>DD</sub> × i(AVERAGE) = 5 × (0.05 × 3500  $\mu$ A + 0.95 × 8  $\mu$ A) = (5 × 182.6)  $\mu$ W = 0.9 mW



#### **MECHANICAL DATA**

### DGK (R-PDSO-G8)

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187

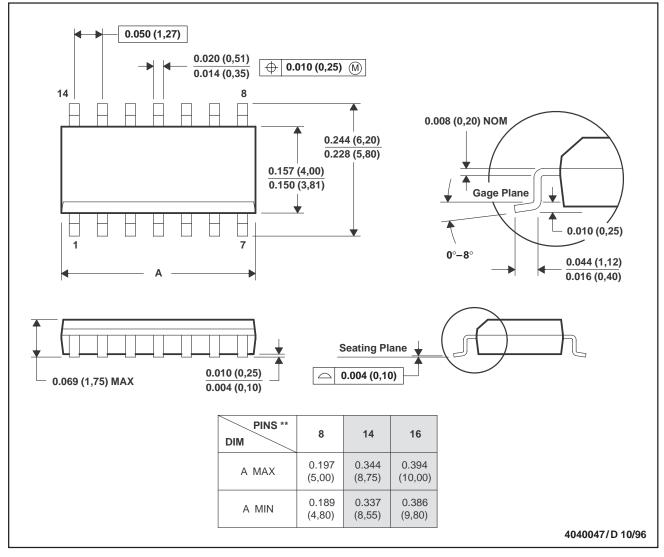


#### **MECHANICAL DATA**

#### D (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE





NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012



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